

## **Features**

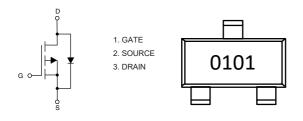
- TrenchFET Power MOSFET
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

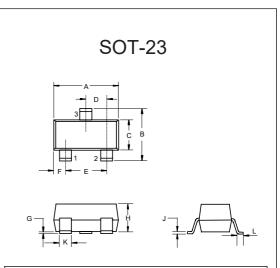
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 162°C/W Junction to Ambient(2.3)

| Parameter                             | Symbol          | Rating | Unit |  |
|---------------------------------------|-----------------|--------|------|--|
| Drain -source Voltage                 | V <sub>DS</sub> | -100   | V    |  |
| Gate -Source Voltage                  | V <sub>GS</sub> | ±20    | V    |  |
| Continuous Drain Current(2.3)         | I <sub>D</sub>  | -1     | Α    |  |
| Continuous Source-Drain Diode Current | I <sub>S</sub>  | -1     | Α    |  |
| Power Dissipation                     | P <sub>D</sub>  | 0.77   | W    |  |

# **Internal Structure and Marking Code**

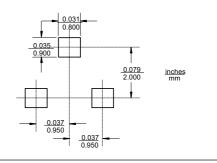


# **P-Channel MOSFET**



| DIMENSIONS |        |       |      |      |      |  |
|------------|--------|-------|------|------|------|--|
| DIM        | INCHES |       | MM   |      | NOTE |  |
| DIIVI      | MIN    | MAX   | MIN  | MAX  | NOTE |  |
| Α          | 0.110  | 0.120 | 2.80 | 3.04 |      |  |
| В          | 0.083  | 0.104 | 2.10 | 2.64 |      |  |
| С          | 0.047  | 0.055 | 1.20 | 1.40 |      |  |
| D          | 0.034  | 0.041 | 0.85 | 1.05 |      |  |
| Е          | 0.067  | 0.083 | 1.70 | 2.10 |      |  |
| F          | 0.018  | 0.024 | 0.45 | 0.60 |      |  |
| G          | 0.0004 | 0.006 | 0.01 | 0.15 |      |  |
| Н          | 0.035  | 0.043 | 0.90 | 1.10 |      |  |
| J          | 0.003  | 0.007 | 0.08 | 0.18 |      |  |
| K          | 0.012  | 0.020 | 0.30 | 0.51 |      |  |
| L          | 0.007  | 0.020 | 0.20 | 0.50 |      |  |

## Suggested Solder Pad Layout





# MOSFET ELECTRICAL CHARACTERISTICS( $T_A = 25^{\circ}C$ unless otherwise noted)

| Parameter                         | Symbol               | Test Condition  | Min  | Type | Max  | Unit |  |
|-----------------------------------|----------------------|---|------|------|------|------|--|
| Off Characteristics               |                      |   |      | •    |      |      |  |
| Drain-source breakdown voltage    | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> = -250µA               | -100 |      |      | V    |  |
| Zero gate voltage drain current   | I <sub>DSS</sub>     | V <sub>DS</sub> = -100V, V <sub>GS</sub> = 0V               |      |      | -1   | μΑ   |  |
| Gate-body leakage current         | lgss                 | V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V                |      |      | ±100 | nA   |  |
| On Characteristics <sup>(4)</sup> |                      |   |      |      |      |      |  |
| Gate threshold voltage            | $V_{GS(th)}$         | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250µA | -1.5 | -2.2 | -3.0 | V    |  |
| Drain-source on-resistance        | Page 1               | V <sub>GS</sub> = -10V, I <sub>D</sub> = -1.0A              |      | 580  | 800  | mΩ   |  |
|                                   | R <sub>DS(on)</sub>  | $V_{GS}$ = -4.5V, $I_D$ = -0.5A                             |      | 650  | 1000 |      |  |
| Dynamic Characteristics           |                      |   |      |      |      |      |  |
| Input Capacitance                 | Ciss                 |   |      | 388  |      | pF   |  |
| Output Capacitance                | Coss                 | $V_{DS} = -40V$ , $V_{GS} = 0V$ , $f = 1MHz$                |      | 19   |      |      |  |
| Reverse Transfer Capacitance      | $C_{rss}$            |   |      | 15   |      |      |  |
| Switching Characteristics         |                      |   |      |      |      |      |  |
| Total Gate Charge                 | Qg                   |   |      | 3.2  |      | nC   |  |
| Gate-Source Charge                | $Q_{gs}$             | $V_{DS}$ =-10V, $V_{GS}$ =-10V, $I_{D}$ = -1A               |      | 0.5  |      |      |  |
| Gate-Drain Charge                 | $Q_{gd}$             |   |      | 1.1  |      |      |  |
| Turn-on delay time                | $t_{d(on)}$          |   |      | 10   |      |      |  |
| Turn-on rise time                 | t <sub>r</sub>       | $V_{DD} = -10V$ , $V_{G} = -10V$ , $ID = -1A$               |      | 32   |      | ns   |  |
| Turn-off delay time               | $t_{d(off)}$         | $R_G = 2.5\Omega$   |      | 28   |      |      |  |
| Turn-off fall time                | t <sub>f</sub>       |   |      | 9    |      |      |  |
| Diode Characteristics             |                      |   |      |      |      |      |  |
| Diode forward current             | Is                   | T <sub>A</sub> = 25℃  |      |      | -1   | Α    |  |
| Diode pulsed forward current      | Isм                  |   |      |      | -4   | Α    |  |
| Diode Forward voltage             | V <sub>DS</sub>      | V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A                  |      |      | -1.2 | V    |  |

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

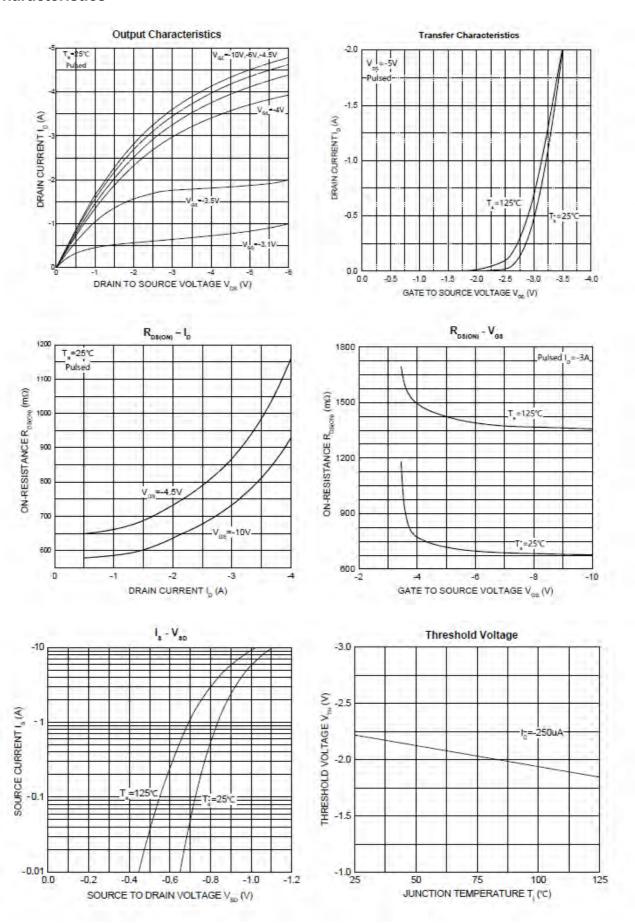
<sup>2.</sup>  $R_{\theta JA}$  is measured with the device mounted on 1 in  $^2$  FR4 board with 1oz. single side copper, in a still air environment with  $T_A = 25^{\circ}C$ .

<sup>3.</sup>  $R_{\theta JA}$  is measured in the steady state

<sup>4.</sup> Pulse test : Pulse width  $\leq$  380µs, duty cycle  $\leq$  2%.



## **Curve Characteristics**





# **Ordering Information**

| Device         | Packing              |
|----------------|----------------------|
| Part Number-TP | Tape&Reel:3Kpcs/Reel |

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